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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> (use as many sheets as necessary)		Application Number	09/894,125
		Filing Date	June 29, 2001
		First Named Inventor	Shunpei YAMAZAKI et al.
		Group Art Unit	2823
		Examiner Name	B. Kebede
		Attorney Docket Number	0756-2330

FOREIGN PATENT DOCUMENTS						
Examiner Initials <sup>1</sup>	Cite No. <sup>2</sup>	Foreign Patent Document		Name of Patent or Application of Claim Document	Date of Publication of Claim Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Office <sup>3</sup>	Kind Code <sup>4</sup> (if known)			
BL		JP	07-130652		05/19/1995	AB

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS						
Examiner Initials <sup>1</sup>	Cite No. <sup>2</sup>	Include name of the author (in CAPITAL LETTERS), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.				
BL		R. Shimokawa et al., <i>Characterization of High-Efficiency Cast-Si Solar Cell Wafers by MBIC Measurement</i> , Japanese Journal of Applied Physics, Volume 27, No. 5, May, 1988, pp. 751-758				
BL		H. Furue et al., <i>P-78: Characteristics and Driving Scheme of Polymer-Stabilized Monostable FLC/D Exhibiting Fast Response Time and High Contrast Ratio with Gray-Scale Capability</i> , SID, 1998				
BL		T. Yoshida, 33.2: <i>A Full-Color Thresholdless Antiferroelectric LCD Exhibiting Wide Viewing Angle with Fast Response Time</i> , SID Digest, 1997, pp. 841-844.				
BL		H. Dorin, et al., <i>Chemistry the Study of Matter</i> , Prentice Hall, Fourth Edition, 1992, p. 532.				
BL		Y. Aya, et al., <i>Improvement of SPC Poly-Si Film Using the ELA Method</i> , 1997 International Workshop on Active-Matrix Liquid-Crystal Displays, September 11-12, 1997, pp. 167-170.				
BL		H. Abe, et al., <i>High-Performance Poly-Crystalline Silicon TFTs Fabricated Using the SPC and ELA Methods</i> , 1998 International Workshop on Active-Matrix Liquid-Crystal Displays, July 9-10, 1998, pp. 85-88.				
BL		S. Inui, et al., <i>Thresholdless Antiferroelectricity in Liquid Crystals and its Application Displays</i> , J. Mater. Chem., 1996, pp. 671-673				

Examiner Signature	B. Kebede	Date Considered	10/12/2003
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